

# **DSF20545SF**

# **Fast Recovery Diode**

DS4152-5 July 2014 (LN31790)

### FEATURES

- Double Side Cooling
- High Surge Capability
- Low Recovery Charge

#### **APPLICATIONS**

• Antiparallel and FWD for GTO

### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>RRM</sub> V	Conditions
DSF20545SF45 DSF20545SF44 DSF20545SF43 DSF20545SF42	4500 4400 4300 4200	$V_{RSM} = V_{RRM}$ +100V
DSF20545SF41 DSF20545SF40	4100 4000	

Lower voltage grades available.

# **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

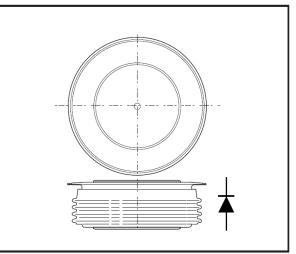
For example:

DSF20545SF44 for a 4400V device

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order

### **KEY PARAMETERS**

V <sub>RRM</sub>	4500V
I <sub>F(AV)</sub>	1256A
I <sub>FSM</sub>	16000A
Qr	1250μC
t <sub>rr</sub>	7.0μs



Outline type code: CB450. See Package Details for further information.

Fig. 1 Package outline

# **CURRENT RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled		1	
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load $T_{case}$ = 65°C	1256	А
I <sub>F(RMS)</sub>	RMS value	T <sub>case</sub> = 65°C -	1971	А
I <sub>F</sub>	Continuous (direct) on-state current	T <sub>case</sub> = 65°C -	1765	А
Single Sic	le Cooled (Anode side)			
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load $T_{case}$ = 65°C -	995	Α
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 65^{\circ}C$	1552	А
١ <sub>F</sub>	Continuous (direct) on-state current	T <sub>case</sub> = 65°C	1335	А

# SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 150°C	12.8	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 50\% V_{RRM}$	819	kA <sup>2</sup> s
I <sub>FSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	16.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_{R} = 0$	1.28	MA <sup>2</sup> s

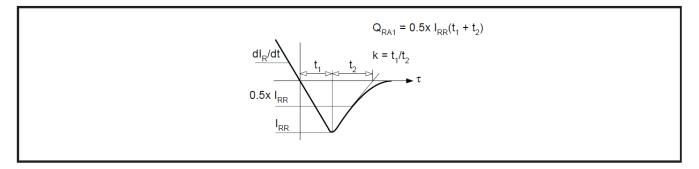
# THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Condition	S	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.022	°C/W
		Single side cooled	Anode DC	-	0.032	°C/W
			Cathode DC	-	0.032	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Clamping force 15kN	Double side	-	0.004	°C/W
		(with mounting compound)	Single side	-	0.008	°C/W
T <sub>vj</sub>	Virtual junction temperature	On-state (conducting)		-	150	°C
		Reverse (blocking)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	150	°C
Fm	Clamping force			17.5	21.5	kN

# CHARACTERISTICS

Symbol	Parameter	Test Conditions	Тур.	Max.	Units
$V_{FM}$	Forward voltage	At 1800A peak, T <sub>case</sub> = 25°C	-	2.1	V
I <sub>RM</sub>	Peak reverse current	At V <sub>DRM</sub> , T <sub>case</sub> = 150°C	-	50	mA
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 1000A, dI <sub>RR</sub> /dt =100A/μs T <sub>case</sub> =150°C, V <sub>R</sub> =100V		7.0	μS
Qs	Total stored charge		-	1250	μC
Irr	Peak reverse recovery current			400	А
К	Softness Factor		1.8	-	-
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 150°C	-	1.36	V
۲ <sub>T</sub>	Slope resistance	At T <sub>vj</sub> =150°C	-	0.47	mΩ
$V_{FRM}$	Forward recovery voltage	$Di/dt = 1000A/us, T_j = 125^{\circ}C$		160	V

# DEFINITION OF K FACTOR AND Q<sub>RA1</sub>



# **DSF20545SF**

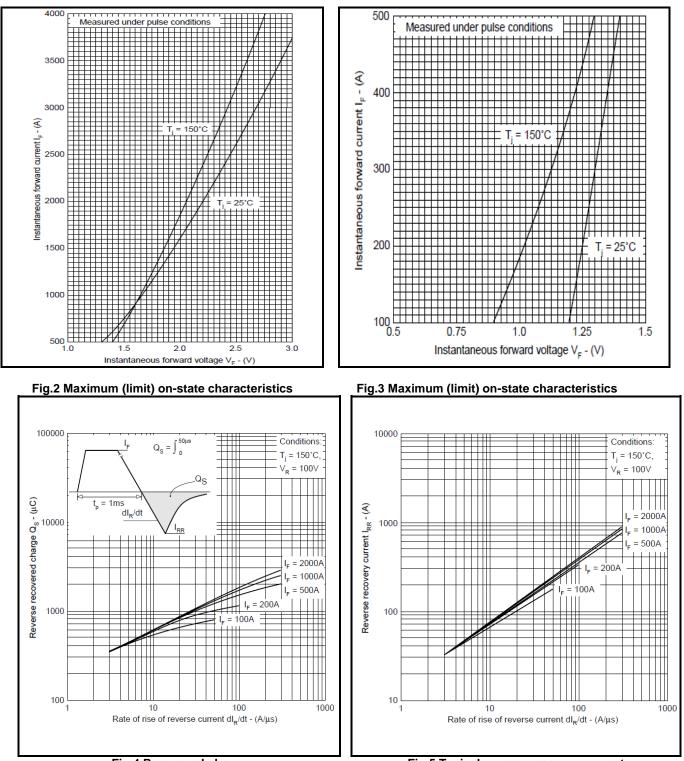


Fig.4 Recovered charge

Fig.5 Typical reverse recovery current

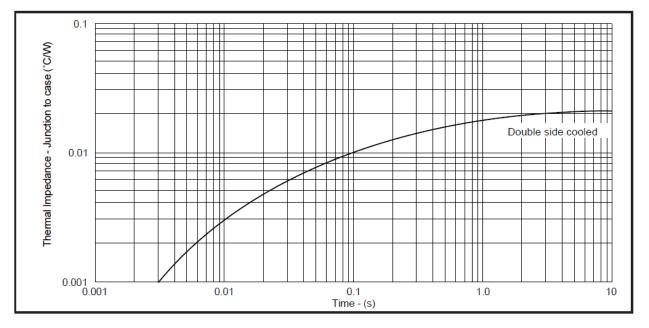
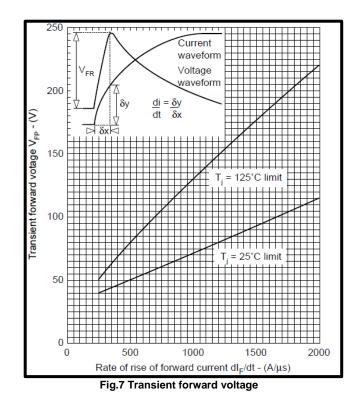
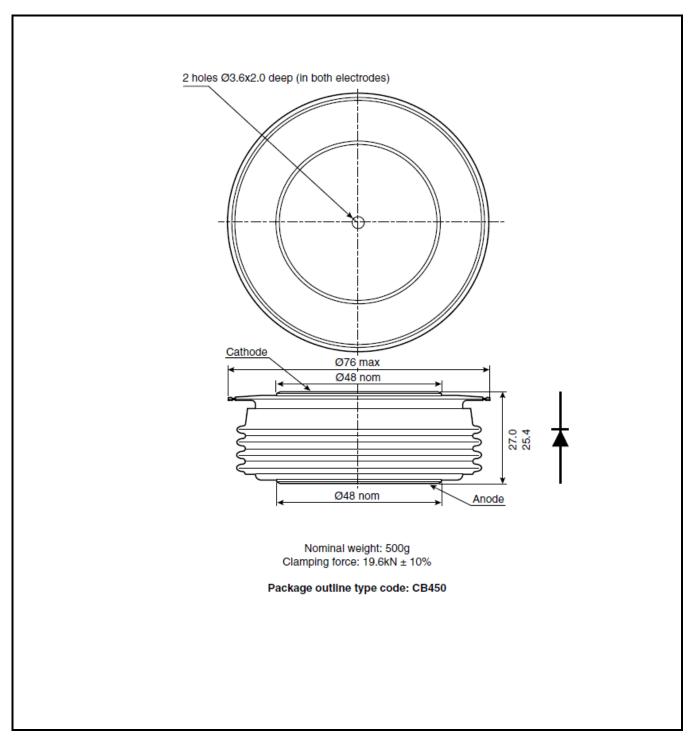


Fig.6 Maximum (limit) transient thermal impedance- junction to case



## PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note: Some packages may be supplied with gate and or tags.

### **DSF20545SF**

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